

Technical Data Data Sheet N1103, Rev. - **Green Products**

MBRB60100CT SCHOTTKY RECTIFIER

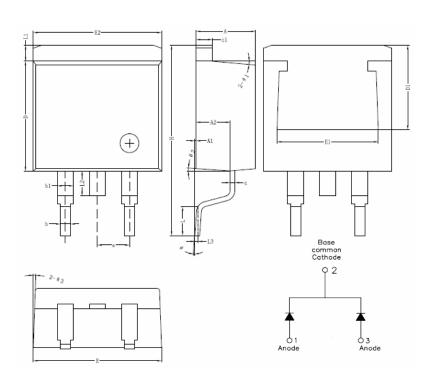
Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Features:

- 150 °C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

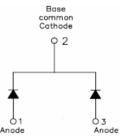
Mechanical Dimensions: In mm



Symbol	Dimensions in millimeters			
	Min.	Typical	Max.	
Α	4.55	4.70	4.85	
A1	0	0.10	0.25	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1		1.27		
С	0.36	0.38	0.61	
c1	1.17	1.27	1.37	
D	8.55	8.70	8.85	
D1	6.40			
E	10.01	10.16	10.31	
E1	7.6			
E2	9.98	10.08	10.18	
е		2.54		
Н	14.6	15.1	15.6	
L	2.00	2.30	2.70	
L1	1.17	1.27	1.40	
L2			2.20	
L3		0.25BSC		
е	0	-	8°	
e1		5°		
e2		4 °		
e3		4°		

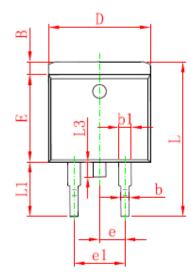
OPTION 1(HD)

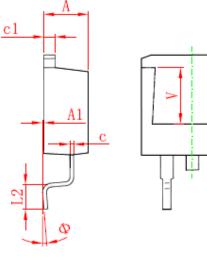
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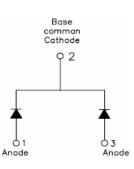


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Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	4.470	4.670	0.176	0.184
A1	0.000	0.150	0.000	0.006
В	1.120	1.420	0.044	0.056
b	0.710	0.910	0.028	0.036
b1	1.170	1.370	0.046	0.054
С	0.310	0.530	0.012	0.021
c1	1.170	1.370	0.046	0.054
D	10.010	10.310	0.394	0.406
E	8.500	8.900	0.335	0.350
e	2.540	TYP.	0.100 TYP.	
e1	4.980	5.180	0.196	0.204
L	14.940	15.500	0.588	0.610
L1	4.950	5.450	0.195	0.215
L2	2.340	2.740	0.092	0.108
L3	1.300	1.700	0.051	0.067
Φ	0°	8°	0°	8°
V	5.600 REF.		0.220	REF.



OPTION 2(CJ)

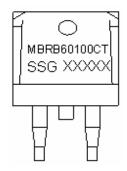
 $D^2 PAK$



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Marking Diagram:



Where XXXXX is YYWWL

MBR	= Device Type
В	= Package type
60	= Forward Current (60A)
100	= Reverse Voltage (100V)
СТ	= Configuration
SSG	= SSG
ΥY	= Year
WW	= Week
L	= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
MBRB60100CT	D ² PAK	800pcs / reel
	(Pb-Free)	oopes / reer

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V _{RWM}	-	100	V
Max. Average Forward	I _{F(AV)}	50% duty cycle @T _C = 135°C, rectangular wave form	60	А
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	Surge applied at rated load conditions halfwave, single phase,60Hz	280	A

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Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop (per leg) *	V _{F1}	@ 30 A, Pulse, T _J = 25 °C	0.90	V
	V_{F2}	@ 30 A, Pulse, T _J = 125 °C	0.81	V
Max. Reverse Current	I _{R1}	@V _R = rated VR T _J = 25 °C	1.0	mA
	I _{R2}	@V _R = rated VR T _J = 125 °C	6.0	mA
Max. Junction Capacitance (per leg)	Ст	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	400	pF
Typical Series Inductance (per leg)	Ls	Measured lead to lead 5 mm from package body	8.0	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/s

* Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature Range	TJ	-	-55 to +150	°C
Storage Temperature Range	T _{stg}	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	2.0	°C/W
Maximum Thermal Resistance, Case to Heat Sink	R _{θJA}	DC operation	50	°C/W
Maximum Thermal Resistance, Case to Heat Sink	R _{0CS}	Mounting surface, smooth and greased	0.50	°C/W
Approximate Weight	wt	-	1.85	g
Case Style	D ² PAK			

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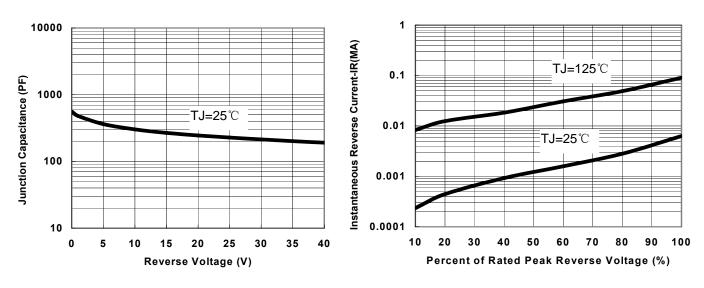




Fig.2-Typical Reverse Characteristics

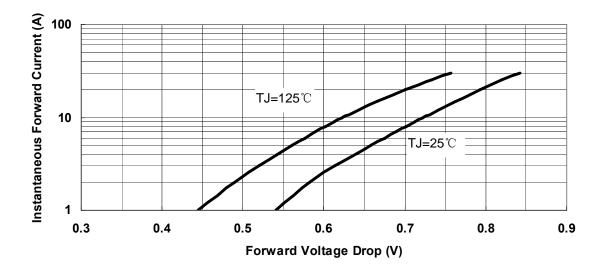


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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